NSN 5961-00-823-9972

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View Online at https://aerobasegroup.com/nsn/5961-00-823-9972 **Inclosure Material:** Metal **Overall Length:** 0.535 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-63 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 8.0 breakdown voltage, emitter-to-base, collector open and 80.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector **Transfer Ratio:** 225.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:**

N/a

3 tab, solder lug Shelf Life:

Unit Of Measure:

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No

Fiig:

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